

Agent's Docket No. 10963-U\$

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re Application of)
RABAH BOUKHERROUB et al	ý
Serial No: 09/803,044) Art Unit: 1765

Filed: 12-March-2001

For: PASSIVATION OF POROUS SEMICONDUCTORS

October 05, 2001

Commissioner of Patent and Trademarks

Washington, D.C. 20231

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Commissioner of Patent and Trademarks

Washington, D.C. 20231

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TRANSMITTAL LETTER C 1700

Please find enclosed for filing:

PRELIMINARY AMENDMENT dated October 05, 2001

Respectfully submitted

Richard J. Mitchell

Reg. No. 34,519

Agent of Record

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Agent's Bocket No. 103

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PRELIMINARY AMENDMENT

Sir:

Please amend the above-referenced application as follows:

IN THE CLAIMS:

Please add new claims 32 to 35 as follows:

- - 32. An electronic/photonic/optoelectronic device comprising a porous silicon structure made by the process defined in claim 1. -
- - 33. An electronic/photonic/optoelectronic device comprising a porous silicon structure made by the process defined in claim 20. -
- - 34. A device comprising a porous silicon structure made by the process defined in claim 1 for the detection of DNA or proteins for genomics and proteomics applications. -
- - 35. A device comprising a porous silicon structure made by the process defined in claim 20 for the detection of DNA or proteins for genomics and proteomics applications. -

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